Description

The AO4405 uses advanced trench

technology to provide excellent $R_{\text{DS}(\text{ON})}$, low gate

charge and operation with gate voltages as low

as 2.5V. This device is suitable for use as a

Battery protection or in other Switching application.



General Features SOP-8

 $V_{DS} = -30 V I_{D} = -6 A$

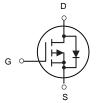
 $R_{DS(ON)}$ < 48m Ω @ V_{GS} =10V

Application

Battery protection

Load switch

Uninterruptible power supply



P-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
AO4405	SOP-8	HXY MOSFET	3000

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	- 30	V
VGS	Gate-Source Voltage	±20	V
ID@TA=25°C	Drain Current ³ , V _{GS} @ 10V	-6	Α
IDM	Pulsed Drain Current ¹	-30	А
P _D @T _A =25°C	Total Power Dissipation	3.1	W
	Linear Derating Factor	0.02	W/°C
TSTG	Storage Temperature Range	-55 to 150	°C
TJ	Operating Junction Temperature Range	-55 to 150	°C
Rthj-a	Maximum Thermal Resistance, Junction-ambient ³	40	°C/W



Electrical Characteristics Ta = 25 ℃

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Drain-Source Breakdown Voltage	VDSS	ID=-250 μ A, VGS=0V	-30			V	
Zero Gate Voltage Drain Current	Ipss	VDS=-30V, VGS=0V			-1	uA	
Zelo Gate Voltage Dialii Guirelli	פסמו	VDS=-30V, VGS=0V, TJ=55℃			-5		
Gate-Body leakage current	Igss	VDS=0V, VGS=±12V			±100	nA	
Gate Threshold Voltage	VGS(th)	VDS=VGS ID=-250 μ A	-0.5		-1.3	V	
	Rds(on)	Vgs=-10V, ID=-6A			48		
Static Drain-Source On-Resistance		Vgs=-10V, Id=-6A TJ=125℃			72	mΩ	
Static Drain-Source On-Resistance		Vgs=-4.5V, ID=-4A			57		
		Vgs=-2.5V, ID=-2A			80		
On state drain current	ID(ON)	Vgs=-4.5V, Vps=-5V	-30			Α	
Forward Transconductance	gFS	VDS=-5V, ID=-6A		19		S	
Input Capacitance	Ciss			645	780	pF	
Output Capacitance	Coss	Vgs=0V, Vps=-15V, f=1MHz		80			
Reverse Transfer Capacitance	Crss			55			
Gate resistance	Rg	Vgs=0V, Vps=0V, f=1MHz	4		12	Ω	
Total Gate Charge	Qg			7			
Gate Source Charge	Qgs	Vgs=-4.5V, Vds=-15V, Id=-6A		1.5		nC	
Gate Drain Charge	Qgd			2.5			
Turn-On DelayTime	td(on)			6.5			
Turn-On Rise Time	tr	Vgs=-10V, Vps=-15V, RL=2.5Ω,		3.5		ns	
Turn-Off DelayTime	td(off)	Rgen=6Ω		41			
Turn-Off Fall Time	tf			9			
Body Diode Reverse Recovery Time	trr	IF=-6A, dı/dt=100A/us		11			
Body Diode Reverse Recovery Charge	Qrr	110A, ul/ul-100A/us		3.5		nC	
Maximum Body-Diode Continuous Current	Is				-3.5	Α	
Diode Forward Voltage	Vsd	Is=-1A,Vgs=0V			-1	V	

Note: The static characteristics in Figures 1 to 6 are obtained using <300 µs pulses, duty cycle 0.5% max.



Typical Characterisitics

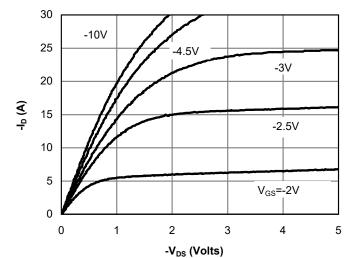
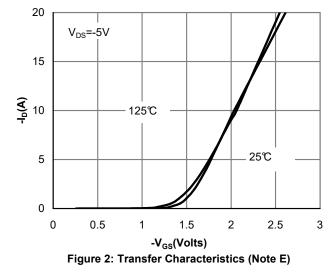


Fig 1: On-Region Characteristics (Note E)



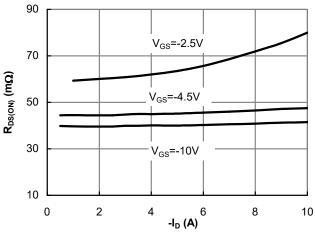


Figure 3: On-Resistance vs. Drain Current and Gate Voltage (Note E)

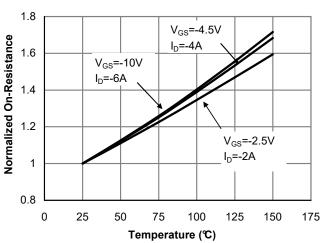


Figure 4: On-Resistance vs. Junction Temperature

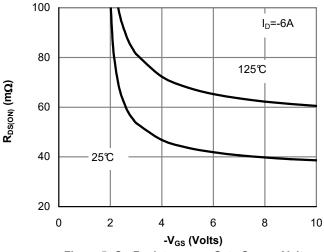


Figure 5: On-Resistance vs. Gate-Source Voltage (Note E)

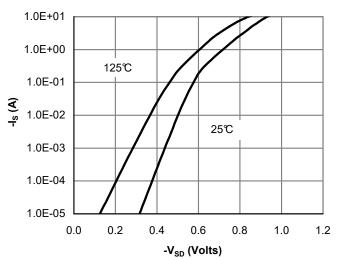
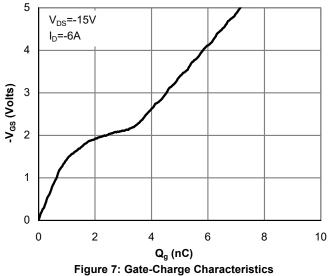


Figure 6: Body-Diode Characteristics (Note E)



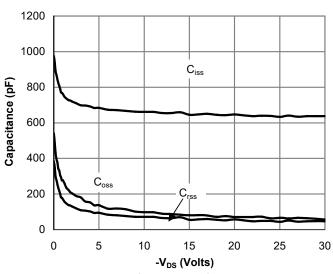


Figure 8: Capacitance Characteristics

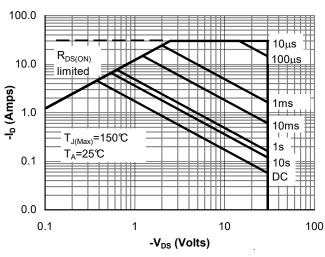


Figure 9: Maximum Forward Biased Safe Operating Area (Note F)

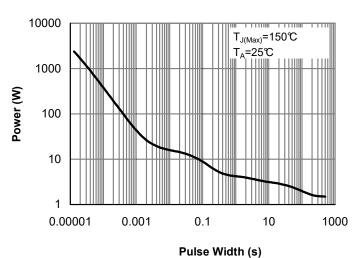


Figure 10: Single Pulse Power Rating Junction-to-Ambient (Note F)

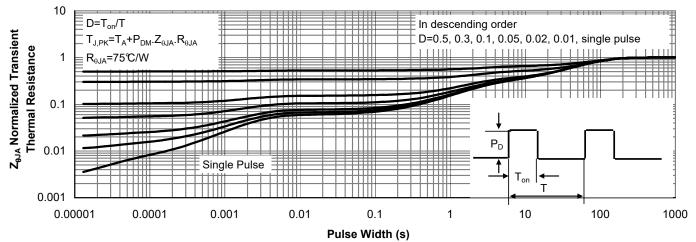
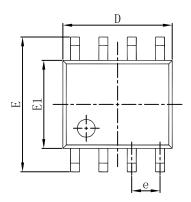
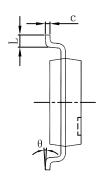


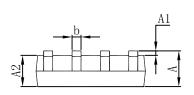
Figure 11: Normalized Maximum Transient Thermal Impedance (Note F)



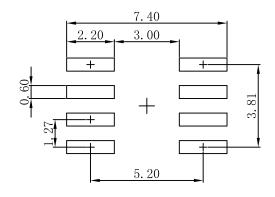
SOP-8 Package Outline Dimensions







Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
A	1.350	1.750	0.053	0.069	
A1	0.100	0. 250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0. 250	0.007	0.010	
D	4.800	5. 000	0. 189	0. 197	
e	1. 270 (BSC)		0.050 (BSC)		
E	5.800	6. 200	0. 228	0. 244	
E1	3.800	4. 000	0. 150	0. 157	
L	0.400	1. 270	0.016	0.050	
θ	0°	8°	0°	8°	



- Note: 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.



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